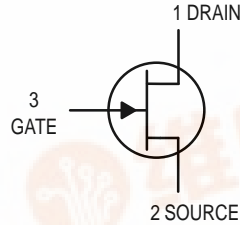
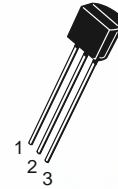


JFET VHF Amplifier

N-Channel — Depletion



MPF102



CASE 29-04, STYLE 5
TO-92 (TO-226AA)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	25	Vdc
Drain-Gate Voltage	V_{DG}	25	Vdc
Gate-Source Voltage	V_{GS}	-25	Vdc
Gate Current	I_G	10	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	350 2.8	mW mW/ $^\circ\text{C}$
Junction Temperature Range	T_J	125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Gate-Source Breakdown Voltage ($I_G = -10 \mu\text{Adc}$, $V_{DS} = 0$)	$V_{(BR)GSS}$	-25	—	Vdc
Gate Reverse Current ($V_{GS} = -15 \text{Vdc}$, $V_{DS} = 0$) ($V_{GS} = -15 \text{Vdc}$, $V_{DS} = 0$, $T_A = 100^\circ\text{C}$)	I_{GSS}	— —	-2.0 -2.0	nAdc μAdc
Gate-Source Cutoff Voltage ($V_{DS} = 15 \text{Vdc}$, $I_D = 2.0 \text{nAdc}$)	$V_{GS(off)}$	—	-8.0	Vdc
Gate-Source Voltage ($V_{DS} = 15 \text{Vdc}$, $I_D = 0.2 \text{mAdc}$)	V_{GS}	-0.5	-7.5	Vdc

ON CHARACTERISTICS

Zero-Gate-Voltage Drain Current ⁽¹⁾ ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0 \text{Vdc}$)	I_{DSS}	2.0	20	mAdc
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SMALL-SIGNAL CHARACTERISTICS

Forward Transfer Admittance ⁽¹⁾ ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 1.0 \text{kHz}$) ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 100 \text{MHz}$)	$ y_{fs} $	2000 1600	7500 —	μhos
Input Admittance ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 100 \text{MHz}$)	$\text{Re}(y_{is})$	—	800	μhos
Output Conductance ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 100 \text{MHz}$)	$\text{Re}(y_{os})$	—	200	μhos
Input Capacitance ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 1.0 \text{MHz}$)	C_{iss}	—	7.0	pF
Reverse Transfer Capacitance ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 1.0 \text{MHz}$)	C_{rss}	—	3.0	pF

1. Pulse Test; Pulse Width $\leq 630 \text{ms}$, Duty Cycle $\leq 10\%$.

POWER GAIN

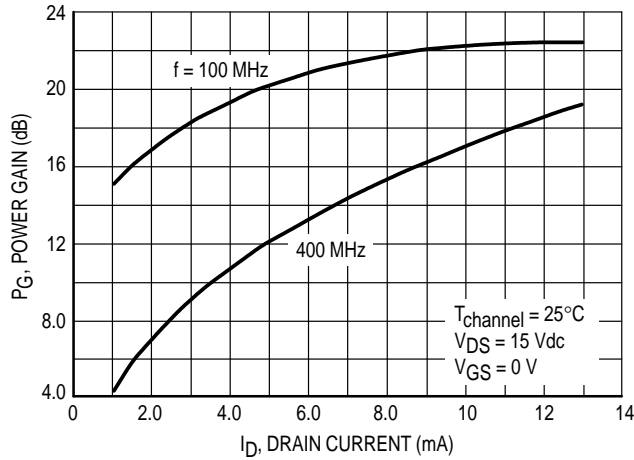
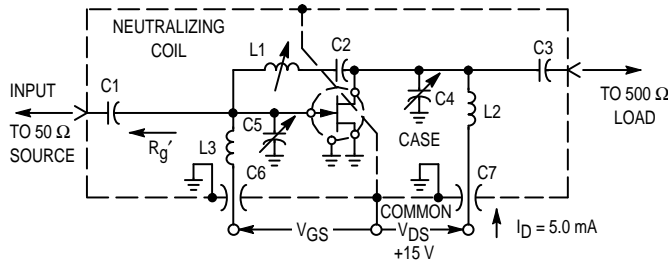


Figure 1. Effects of Drain Current



Adjust V_{GS} for
 $I_D = 50 \text{ mA}$
 $V_{GS} < 0 \text{ Volts}$

NOTE: The noise source is a hot-cold body (AIL type 70 or equivalent) with a test receiver (AIL type 136 or equivalent).

Reference Designation	VALUE	
	100 MHz	400 MHz
C1	7.0 pF	1.8 pF
C2	1000 pF	17 pF
C3	3.0 pF	1.0 pF
C4	1-12 pF	0.8-8.0 pF
C5	1-12 pF	0.8-8.0 pF
C6	0.0015 μF	0.001 μF
C7	0.0015 μF	0.001 μF
L1	3.0 μH^*	0.2 μH^{**}
L2	0.15 μH^*	0.03 μH^{**}
L3	0.14 μH^*	0.022 μH^{**}

- *L1 17 turns, (approx. — depends upon circuit layout) AWG #28 enameled copper wire, close wound on 9/32" ceramic coil form. Tuning provided by a powdered iron slug.
- L2 4-1/2 turns, AWG #18 enameled copper wire, 5/16" long, 3/8" I.D. (AIR CORE).
- L3 3-1/2 turns, AWG #18 enameled copper wire, 1/4" long, 3/8" I.D. (AIR CORE).

- **L1 6 turns, (approx. — depends upon circuit layout) AWG #24 enameled copper wire, close wound on 7/32" ceramic coil form. Tuning provided by an aluminum slug.
- L2 1 turn, AWG #16 enameled copper wire, 3/8" I.D. (AIR CORE).
- L3 1/2 turn, AWG #16 enameled copper wire, 1/4" I.D. (AIR CORE).

Figure 2. 100 MHz and 400 MHz Neutralized Test Circuit

NOISE FIGURE

($T_{channel} = 25^{\circ}C$)

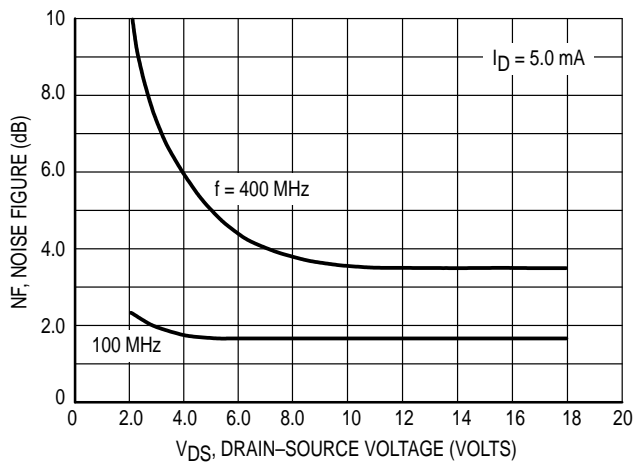


Figure 3. Effects of Drain-Source Voltage

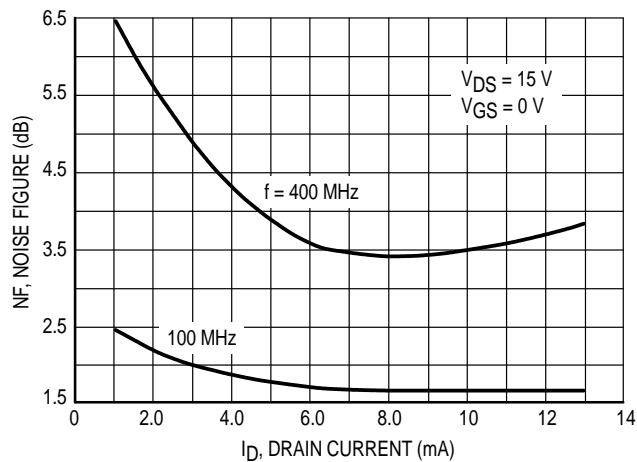


Figure 4. Effects of Drain Current

INTERMODULATION CHARACTERISTICS

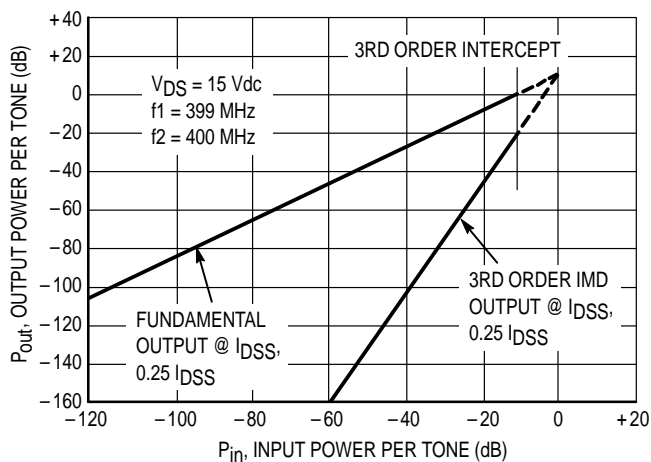


Figure 5. Third Order Intermodulation Distortion

COMMON SOURCE CHARACTERISTICS
ADMITTANCE PARAMETERS
 (V_{DS} = 15 Vdc, T_{channel} = 25°C)

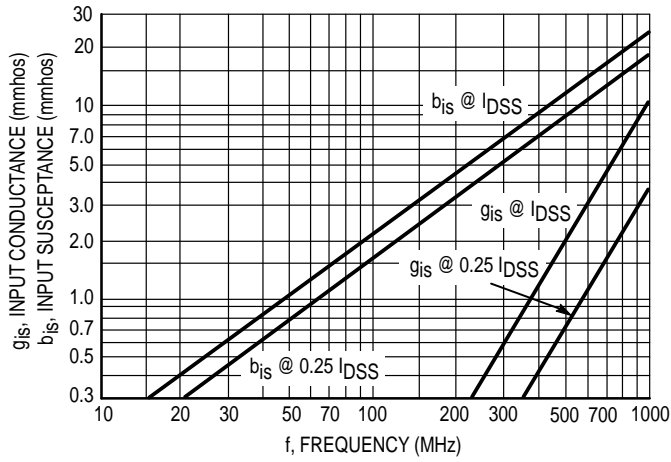


Figure 6. Input Admittance (y_{is})

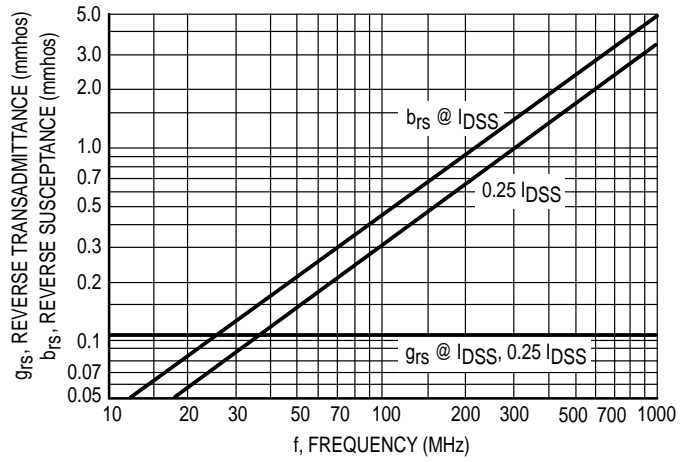


Figure 7. Reverse Transfer Admittance (y_{rs})

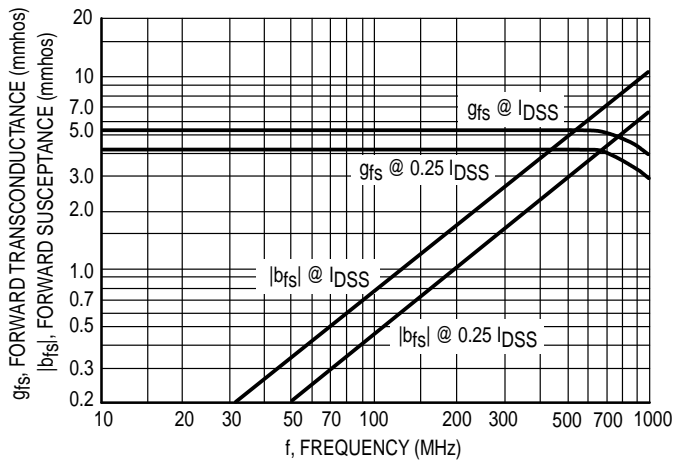


Figure 8. Forward Transadmittance (y_{fs})

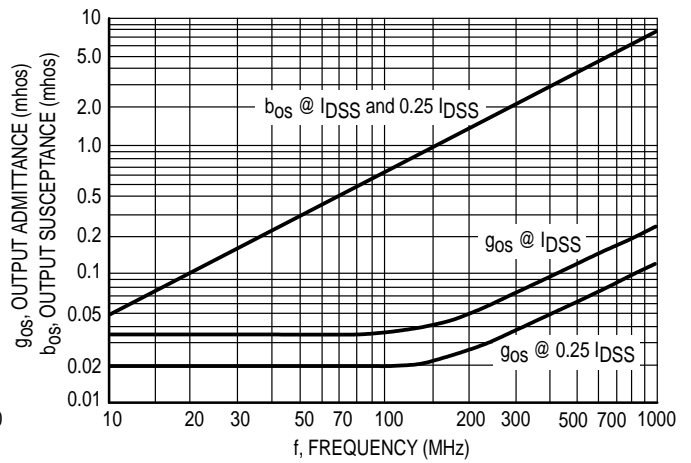


Figure 9. Output Admittance (y_{os})

COMMON SOURCE CHARACTERISTICS
S-PARAMETERS
 ($V_{DS} = 15 \text{ Vdc}$, $T_{\text{channel}} = 25^\circ\text{C}$, Data Points in MHz)

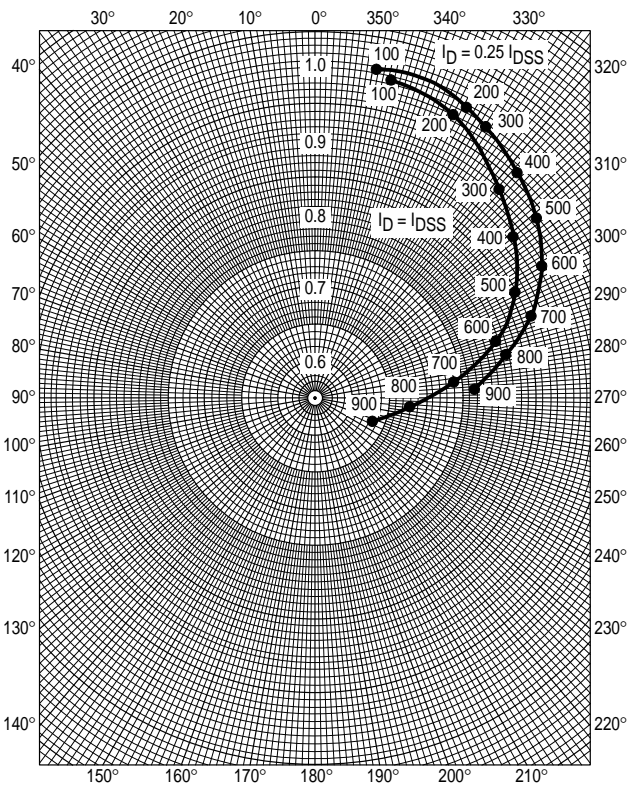


Figure 10. S_{11s}

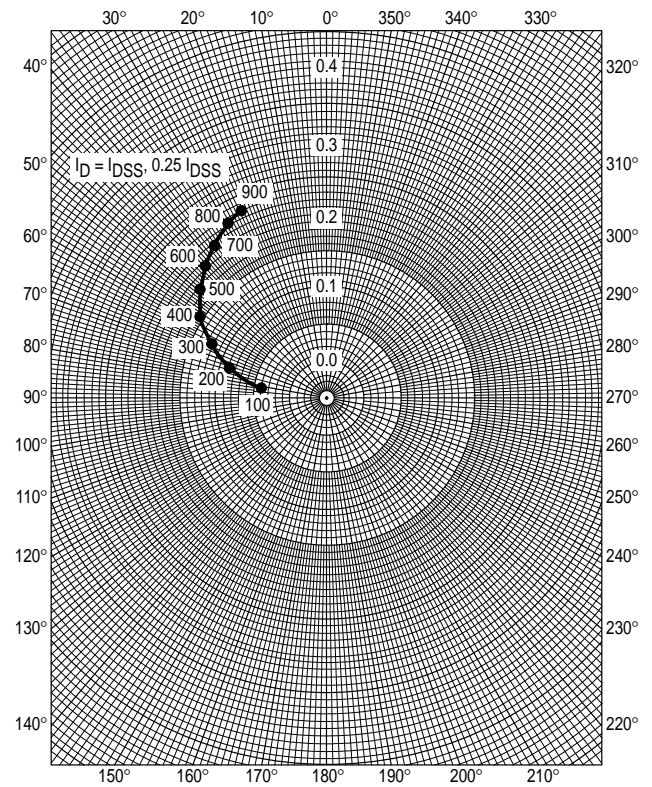


Figure 11. S_{12s}

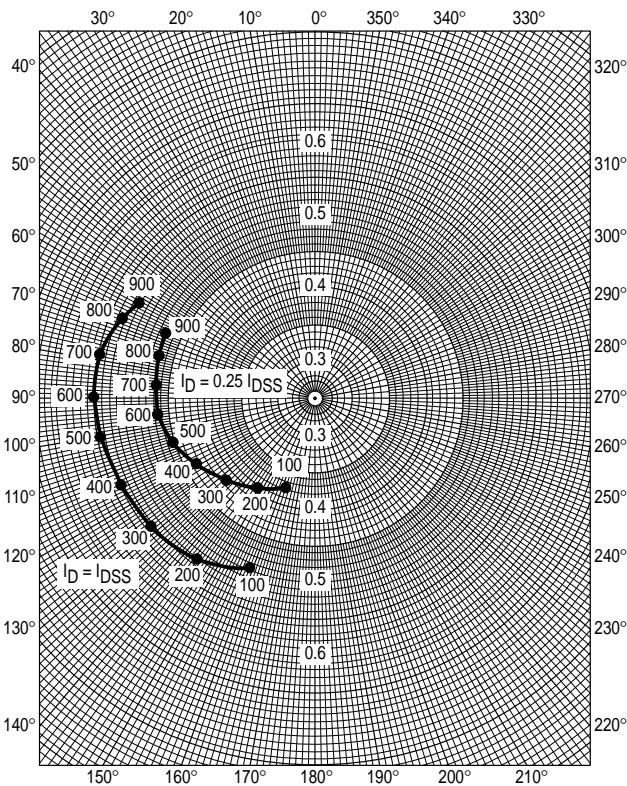


Figure 12. S_{21s}

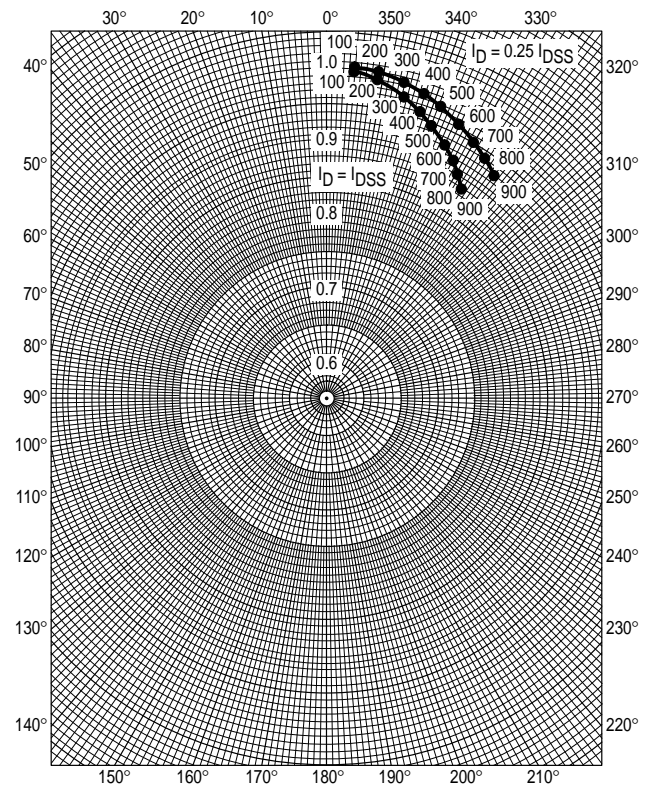


Figure 13. S_{22s}

COMMON GATE CHARACTERISTICS
ADMITTANCE PARAMETERS
 (V_{DG} = 15 Vdc, T_{channel} = 25°C)

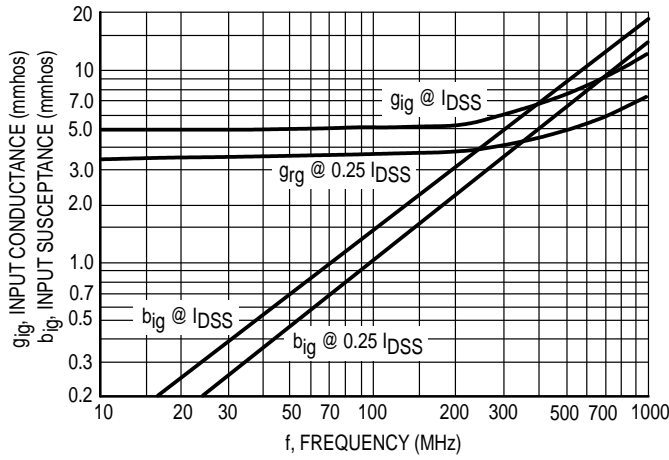


Figure 14. Input Admittance (y_{ig})

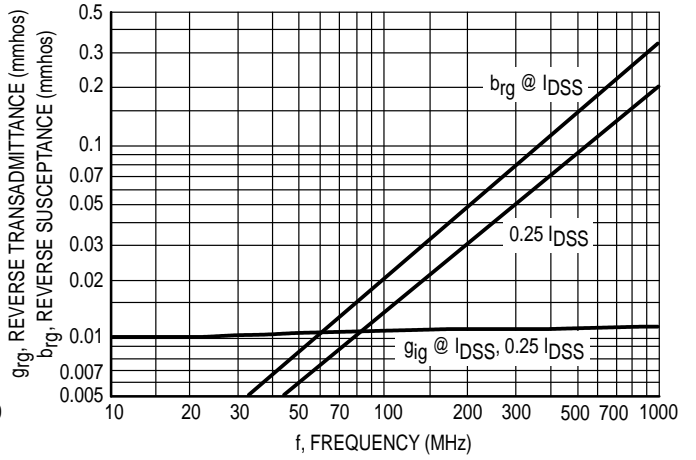


Figure 15. Reverse Transfer Admittance (y_{rg})

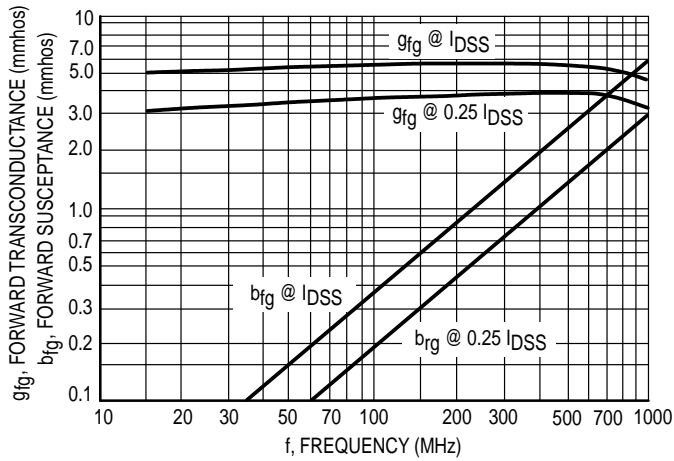


Figure 16. Forward Transfer Admittance (y_{fg})

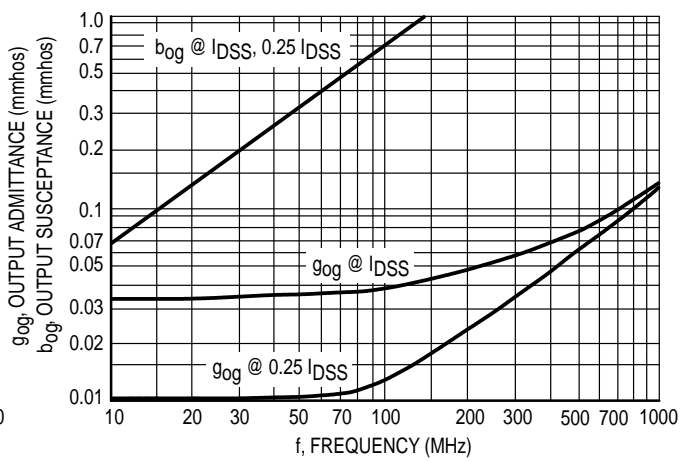


Figure 17. Output Admittance (y_{og})

COMMON GATE CHARACTERISTICS
S-PARAMETERS
 ($V_{DS} = 15 \text{ Vdc}$, $T_{\text{channel}} = 25^\circ\text{C}$, Data Points in MHz)

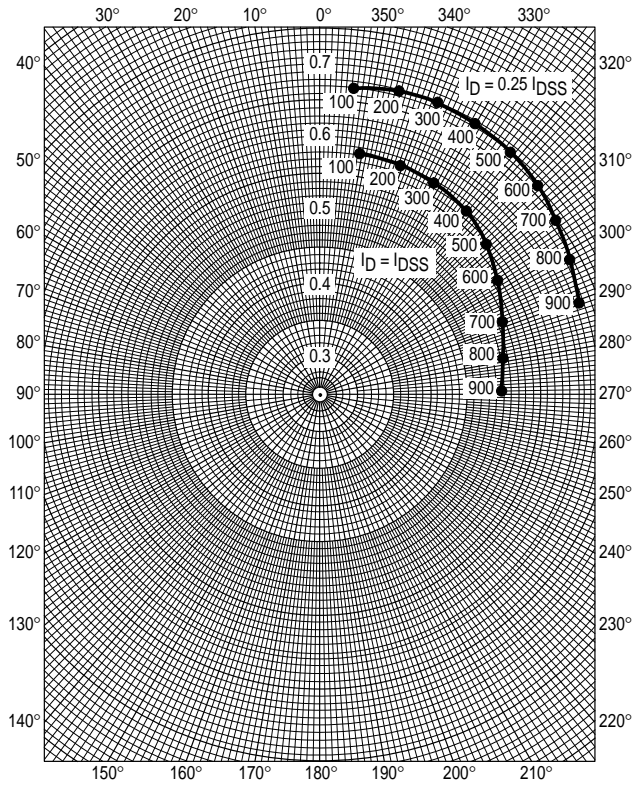


Figure 18. S_{11g}

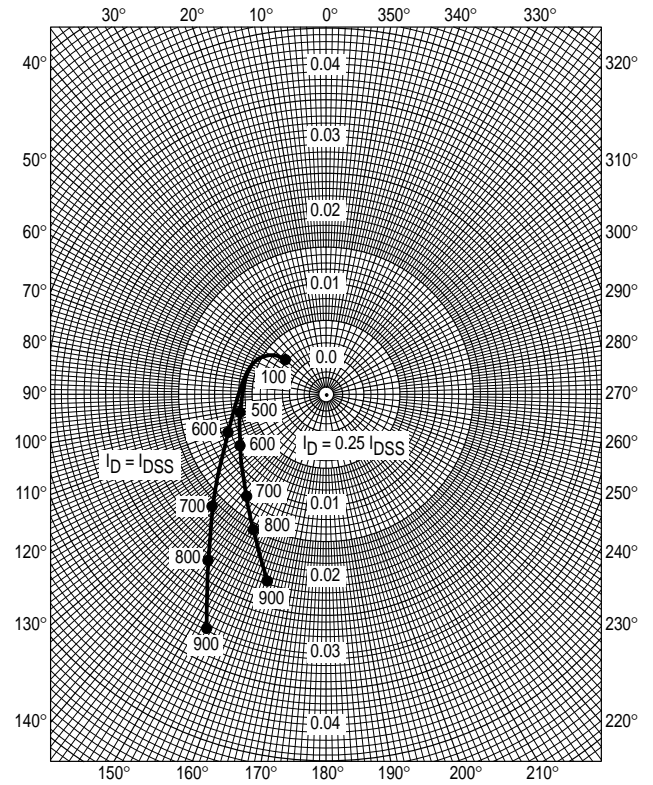


Figure 19. S_{12g}

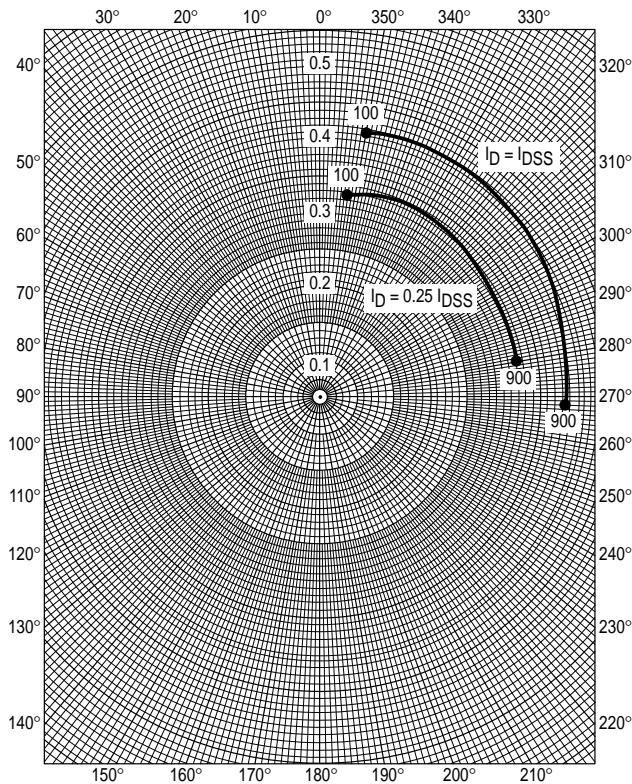


Figure 20. S_{21g}

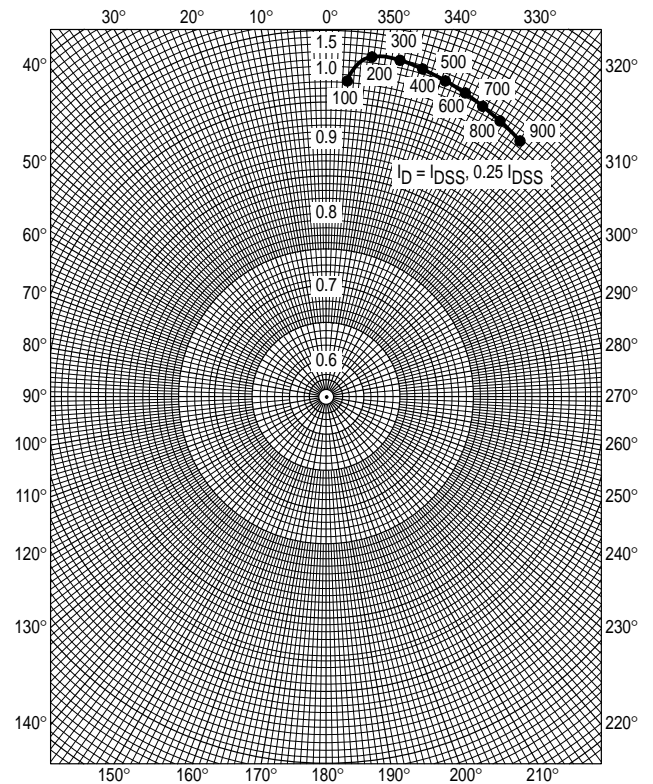
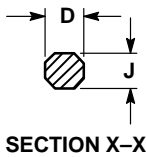
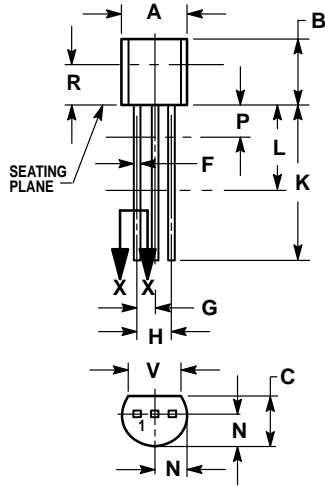


Figure 21. S_{22g}

PACKAGE DIMENSIONS




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

CASE 029-04
(TO-226AA)
ISSUE AD

- STYLE 5:
PIN 1. DRAIN
2. SOURCE
3. GATE

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